

ANTREX Electronics

Electronic Components Sourcing Information

Product Reference Information

Part Number: MBRS140TR
Manufacturer: Vishay General Semiconductor - Diodes Division
Package: DO-214AA, SMB
Availability: Please confirm with sales

Product Page:

<https://antrexco.com/product/details/vishay-general-semiconductor-diodes-division-mbrs140tr.html>

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Contact Information

Email: info@antrexco.com

WhatsApp: +86-186-8066-5326

Website: <https://antrexco.com>

Quality & Trust

New & Original Components

Supplier verification and packaging condition review

CoC / RoHS / REACH documents available on request

Secure sourcing support for OEM / EMS projects

Note:

This PDF includes an ANTREX product reference cover page.

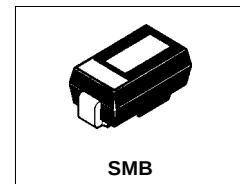
The original manufacturer datasheet follows from the next page.

International
IR Rectifier

MBRS140TR

SCHOTTKY RECTIFIER

1 Amp



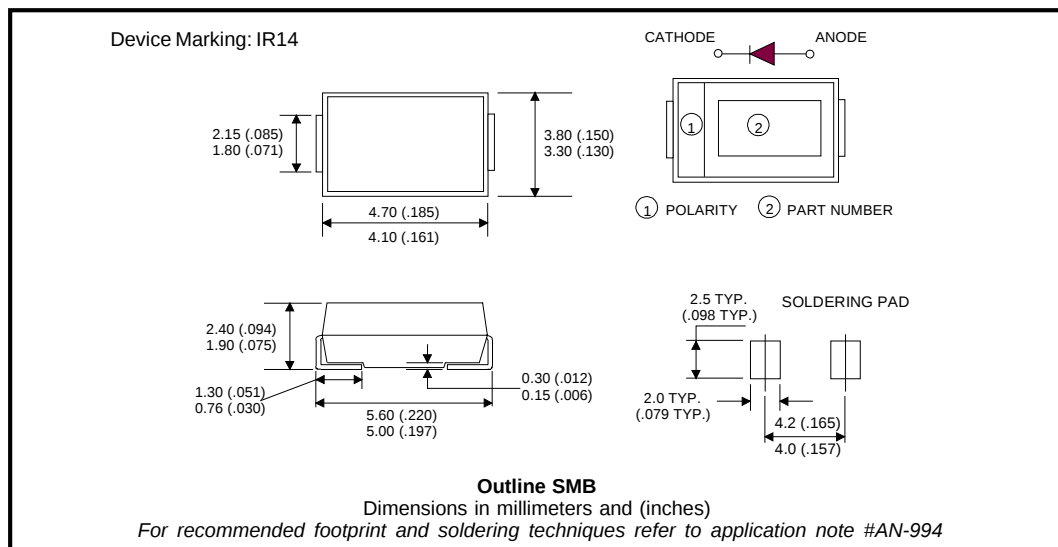
Major Ratings and Characteristics

Characteristics	MBRS140TR	Units
$I_{F(AV)}$ Rectangular waveform	1.0	A
V_{RRM}	40	V
I_{FSM} @ $t_p = 5 \mu s$ sine	380	A
V_F @ 1.0 Apk, $T_J = 125^\circ C$	0.53	V
T_J range	-55 to 150	$^\circ C$

Description/ Features

The MBRS140TR surface-mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging, and reverse battery protection.

- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



MBRS140TR

Bulletin PD-20591 rev. C 03/03

International
IR Rectifier

Voltage Ratings

Part number	MBRS140TR
V_R Max. DC Reverse Voltage (V)	40
V_{RWM} Max. Working Peak Reverse Voltage (V)	

Absolute Maximum Ratings

Parameters		Value	Units	Conditions		
I _{F(AV)}	Max. Average Forward Current	1.0	A	50% duty cycle @ T _L = 119 °C, rectangular wave form		
I _{FSM}	Max. Peak One Cycle Non-Repetitive	380	A	5μs Sine or 3μs Rect. pulse	Following any rated load condition and with rated V _{RRM} applied	
	Surge Current	40		10ms Sine or 6ms Rect. pulse		
E _{AS}	Non- Repetitive Avalanche Energy	3.0	mJ	T _J = 25 °C, I _{AS} = 1A, L = 6mH		
I _{AR}	Repetitive Avalanche Current	1.0	A	Current decaying linearly to zero in 1μsec Frequency limited by T _J max. Va = 1.5 x Vr typical		

Electrical Specifications

Parameters			Typ.	Max	Units	Conditions	
V _{FM} Max. Forward Voltage Drop (1)	0.52	0.6	V	@ 1A	T _J = 25 °C		
	0.70	0.77	V	@ 2A			
	0.48	0.53	V	@ 1A	T _J = 125 °C		
	0.63	0.71	V	@ 2A			
I _{RM} Max. Reverse Leakage Current (1)	-	0.1	mA	T _J = 25°C	V _R = rated V _R		
	-	4.0	mA	T _J = 125°C			
C _T Max. Junction Capacitance	-	80	pF	V _R = 5V _{DC} (test signal range 100KHz to 1Mhz)25°C			
L _S Typical Series Inductance	-	2.0	nH	Measured lead to lead 5mm from package body			
dv/dt Max. Voltage Rate of Change (Rated V _R)	-	10000	V/μs				

(1) Pulse Width < 300 μs , Duty Cycle < 2%

Thermal-Mechanical Specifications

Parameters	Value	Units	Conditions
T_J Max. Junction Temperature Range(*)	-55 to 150	$^\circ\text{C}$	
T_{stg} Max. Storage Temperature Range	-55 to 150	$^\circ\text{C}$	
R_{thJL} Max. Thermal Resistance Junction to Lead (**)	36	$^\circ\text{C/W}$	DC operation (See Fig. 4)
R_{thJA} Max. Thermal Resistance Junction to Ambient	80	$^\circ\text{C/W}$	DC operation
wt Approximate Weight	0.10 (0.003)	g (oz.)	
Case Style	SMB		Similar to DO-214AA
Device Marking	IR14		

(*) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{th}(j-a)}$ thermal runaway condition for a diode on its own heatsink

(**) Mounted 1 inch square PCB

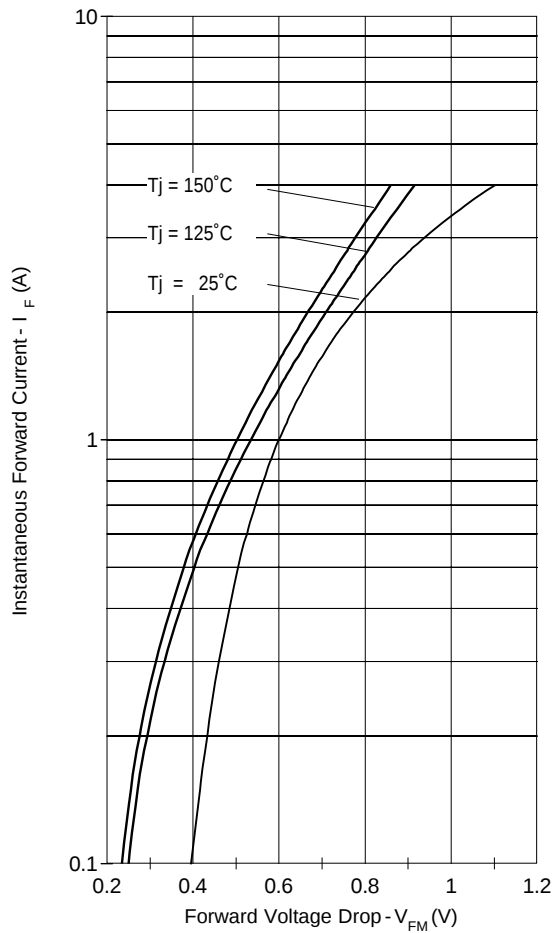


Fig. 1 - Maximum Forward Voltage Drop Characteristics

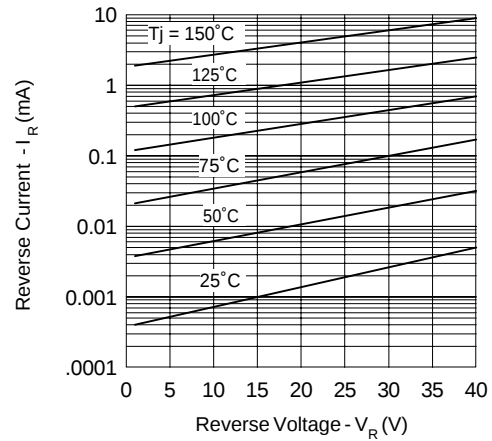


Fig. 2 - Typical Peak Reverse Current Vs. Reverse Voltage

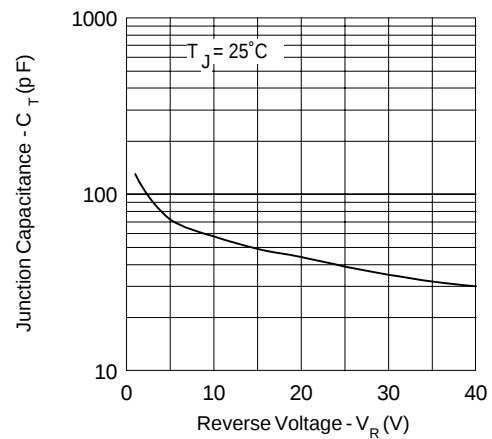


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

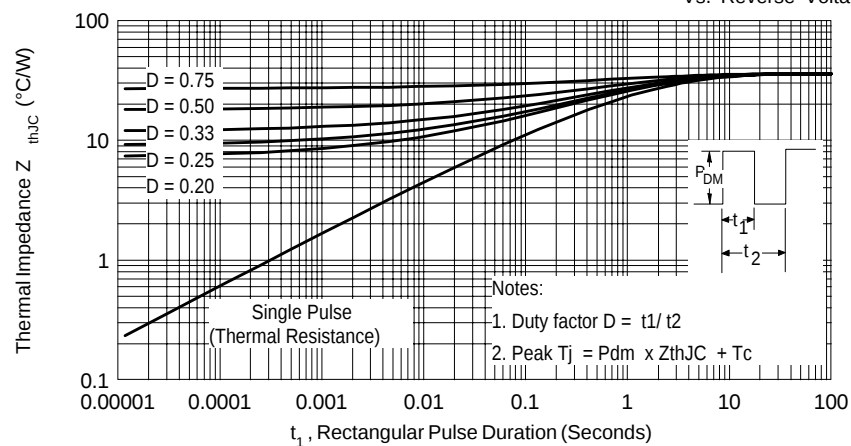


Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics (Per Leg)

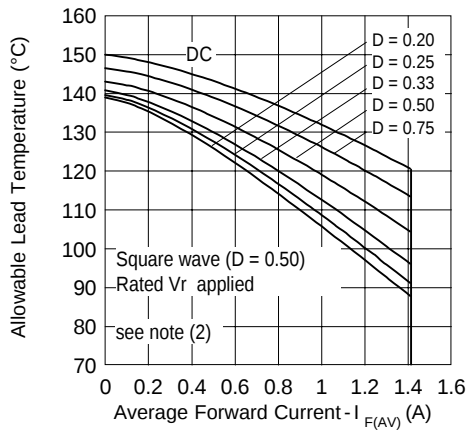


Fig. 4 - Maximum Average Forward Current Vs. Allowable Lead Temperature

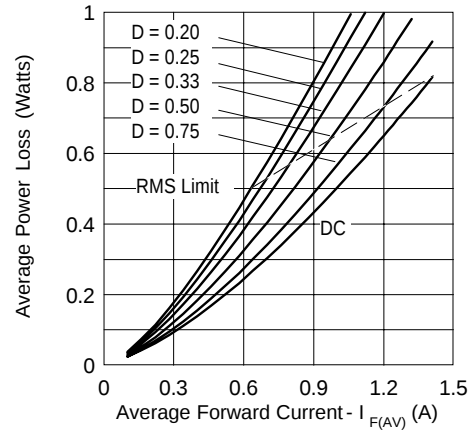


Fig. 5 - Maximum Average Forward Dissipation Vs. Average Forward Current

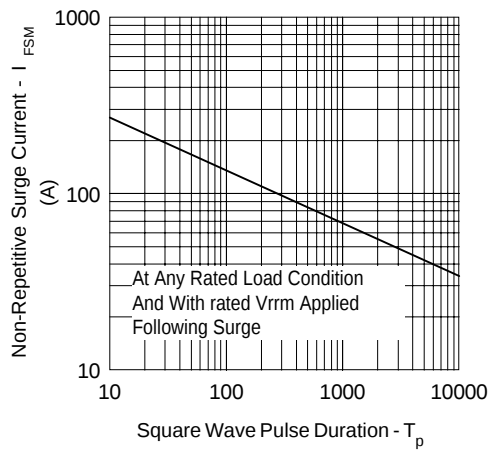


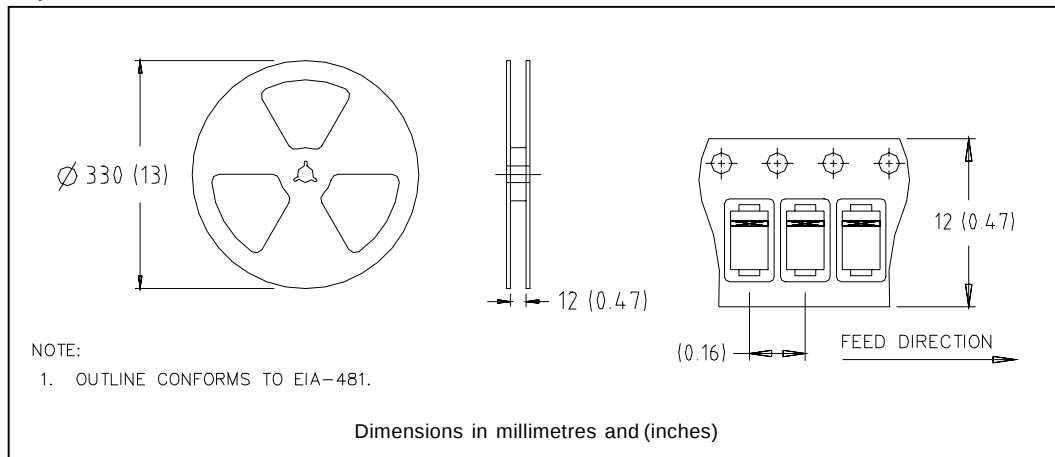
Fig. 6 - Maximum Peak Surge Forward Current Vs. Pulse Duration

(2) Formula used: $T_c = T_j - (P_d + P_{d_{REV}}) \times R_{thJC}$;

P_d = Forward Power Loss = $I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 6);

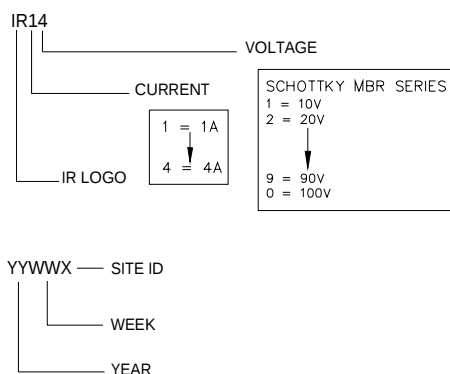
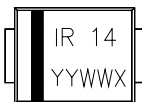
$P_{d_{REV}}$ = Inverse Power Loss = $V_{R1} \times I_R (1 - D)$; $I_R @ V_{R1} = 80\% \text{ rated } V_R$

Tape & Reel Information



Marking & Identification

Each device has 2 rows for identification. The first row designates the device as manufactured by International Rectifier as indicated by the letters "IR", and the Part Number (indicates the current and the voltage rating). The second row indicates the year, the week of manufacturing and the Site ID.



Ordering Information

MBRS140TR - TAPE AND REEL

WHEN ORDERING, INDICATE THE PART NUMBER AND THE QUANTITY (IN MULTIPLES OF 3000 PIECES).

EXAMPLE: MBRS140TR - 6000 PIECES

MBRS140TR

Bulletin PD-20591 rev. C 03/03

International
IOR Rectifier

Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level.
Qualification Standards can be found on IR's Web site.

International
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IR WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245, USA Tel: (310) 252-7105
TAC Fax: (310) 252-7309
Visit us at www.irf.com for sales contact information. 03/03